

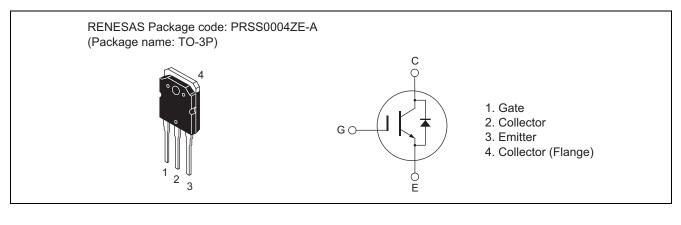
RJH60F5DPK

Silicon N Channel IGBT High Speed Power Switching

Features

- High speed switching
- Low on-state voltage
- Fast recovery diode

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$ Item Symbol Ratings Unit Collector to emitter voltage VCES 600 V V ±30 Gate to emitter voltage V_{GES} Collector current Tc = 25 °C 80 Α lc Tc = 100 °C 40 А lc ic(peak) Note1 Collector peak current 160 А i_{DF}(peak)^{Note2} Collector to emitter diode forward peak current 100 А 260.4 W Collector dissipation P_{C} Junction to case thermal impedance (IGBT) 0.48 °C/W θj-c Junction to case thermal impedance (Diode) °C/W θj-c 2.0 Junction temperature 150 °C Тj Storage temperature Tstg -55 to +150 °C

Notes: 1. Pulse width limited by safe operating area.

2. PW \leq 5 μ s, duty cycle \leq 1%

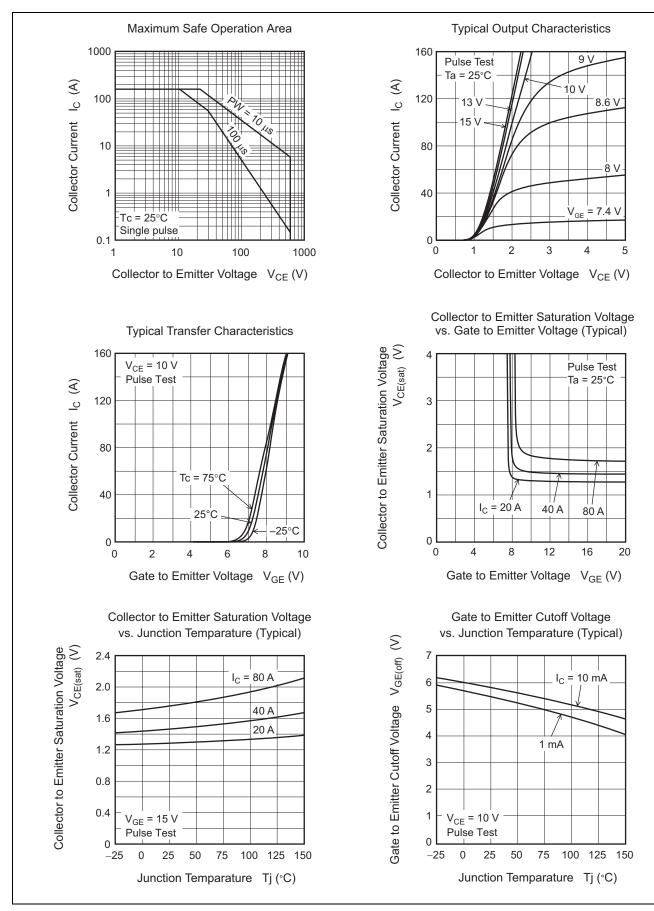
REJ03G1836-0100

Electrical Characteristics

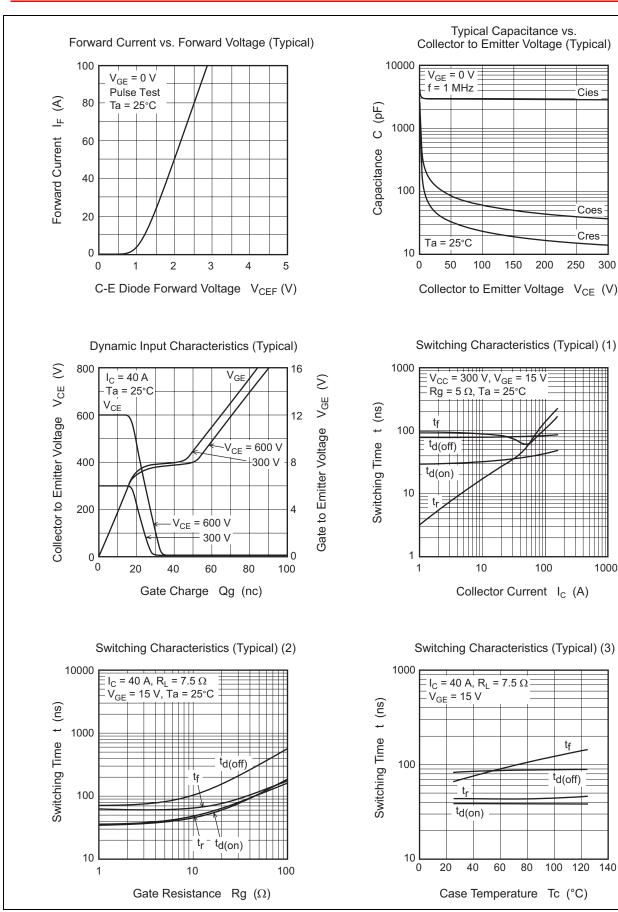
						(Tj = 25°C)
Item	Symbol	Min	Тур	Мах	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}		_	100	μA	V _{CE} = 600V, V _{GE} = 0
Gate to emitter leak current	I _{GES}		_	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V _{GE(off)}	4		8	V	V _{CE} = 10V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}		1.37	1.8	V	I_{C} = 40 A, V_{GE} = 15V ^{Note3}
	V _{CE(sat)}		1.7		V	I_{C} = 80 A, V_{GE} = 15V ^{Note3}
Input capacitance	Cies		2880		pF	V _{CE} = 25 V
Output capacitance	Coes		122		pF	V _{GE} = 0 V
Reverse transfer capacitance	Cres		47		pF	f = 1 MHz
Switching time	t _{d(on)}		40		ns	I _C = 30 A, Resistive Load
	tr		35		ns	V _{CC} = 300 V
	t _{d(off)}		80		ns	$V_{GE} = 15 V$
	t _f		80		ns	$Rg = 5 \Omega^{Note3}$
C-E diode forward voltage	V _{ECF1}		1.6	2.1	V	I _F = 20 A ^{Note3}
	V _{ECF2}		1.8		V	$I_F = 40 \text{ A}^{\text{Note3}}$
C-E diode reverse recovery time	t _{rr}		140		ns	I _F = 20 A
						di _F /dt = 100 A/µs

Notes: 3. Pulse test

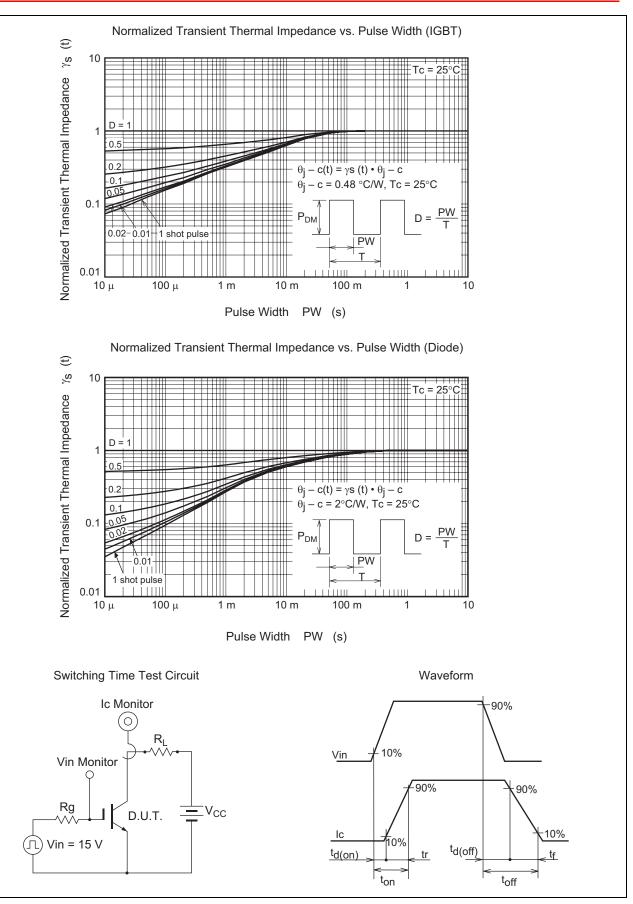
Main Characteristics



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RENESAS



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Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	
Package Name TO-3P	SC-65	PRSS0004ZE-A	TO-3P / TO-3PV	5.0g	11-14
	<u>1.6</u> <u>1.4 Ma</u>	15.6 ± 0.3	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		2
	<u>5.45 ± 0</u>		<u>.0</u> <u>.0</u> <u></u> <u>5.45 ± 0.5</u>		

Ordering Information

Part No.	Quantity	Shipping Container
RJH60F5DPK-00-T0	360 pcs	Box (Tube)

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